# NSN 5962-01-331-4112

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## Overall Height:

0.400 inches

#### **Body Length:**

0.840 inches

### Body Width:

Between 0.220 inches and 0.310 inches

#### **Body Height:**

Between 0.140 inches and 0.185 inches

#### **Maximum Power Dissipation Rating:**

739.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **Features Provided:**

Bipolar and schottky and programmable and monolithic and 3-state output and high impedance

#### Inclosure Material:

Ceramic

#### Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

#### Input Circuit Pattern:

6 input

#### **Case Outline Source And Designator:**

D-2 mil-m-38510

#### **Terminal Surface Treatment:**

Solder

#### Voltage Rating And Type Per Characteristic:

7.0 volts power source

#### **Time Rating Per Chacteristic:**

80.00 nanoseconds propagation delay time, low to high level output and 80.00 nanoseconds propagation delay time, high to low level

output

#### Memory Device Type:

Prom

#### Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

#### Unit Of Measure:

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### Demilitarization:

Yes - demil/mli

Fiig:

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